

Fig 7

365 / 205

154, 189.05

7m 2

	U	1	Document ID	Issue Dat	Pages	Title	Current OR	Current XR	Retrieval	Inventor
1	<input checked="" type="checkbox"/>	<input checked="" type="checkbox"/>	US 20040130	20040708	30	Semiconductor memory de	365/145			Nakase, Yasuno
2	<input checked="" type="checkbox"/>	<input checked="" type="checkbox"/>	US 5886919	19990323	22	Multi-port semiconducto	365/69	257/E27.09		Morikawa, Koui
3	<input checked="" type="checkbox"/>	<input checked="" type="checkbox"/>	US 5773892	19980630	22	Multi-port semiconducto	257/758	257/775;		Morikawa, Koui
4	<input checked="" type="checkbox"/>	<input checked="" type="checkbox"/>	US 5724292	19980303	49	Static Semiconductor me	365/207	365/154;		Wada, Tomohisa
5	<input checked="" type="checkbox"/>	<input checked="" type="checkbox"/>	US 5659515	19970819	40	Semiconductor memory de	365/222	365/230.03		Matsuo, Ryuich
6	<input checked="" type="checkbox"/>	<input checked="" type="checkbox"/>	US 5659513	19970819	91	Static semiconductor me	365/205	327/51;		Hirose, Toshih
7	<input checked="" type="checkbox"/>	<input checked="" type="checkbox"/>	US 5629900	19970513	91	Semiconductor memory de	365/230.03	365/189.01		Hirose, Toshih
8	<input checked="" type="checkbox"/>	<input checked="" type="checkbox"/>	US 5544105	19960806	91	Static semiconductor me	365/189.11	365/189.01		Hirose, Toshih

File View Edit Tools Window Help



Drafts

ISNR:

Pending

Active

L2: (0) "10677012"

L3: (1) "10/677012"

L1: (1749) (365/205).CCLS.

Failed

Saved

Favorites

Tagged (0)

UDC

Queue

Trash

Search

Lib

Browse

Queue

DBs

USPAT; US-PGPUB; EPO; JPO; DERM

☒ Highlight all hit terms initially

365/205

EAST

ISNR

Image

Text

HTML

	U	1	Document ID	Issue Dat	Pages	Title	Current OR	Current
14	<input type="checkbox"/>	<input type="checkbox"/>	US 20040100	20040527	21	Semiconductor memory de	365/205	
15	<input type="checkbox"/>	<input type="checkbox"/>	US 20040100	20040527	16	Semiconductor memory de	365/205	
16	<input type="checkbox"/>	<input type="checkbox"/>	US 20040095	20040520	36	Semiconductor memory de	365/205	365/2
17	<input type="checkbox"/>	<input type="checkbox"/>	US 20040095	20040520	11	Sensing circuit	365/205	

☒ Hits
 ☐ Details
 ☐ HTML

Ready

NUM